# 74HC4049

# Hex inverting HIGH-to-LOW level shifter

Rev. 6 — 8 January 2013

**Product data sheet** 

## 1. General description

The 74HC4049 is a hex inverter with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

#### 2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2 000 V
  - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

# 3. Ordering information

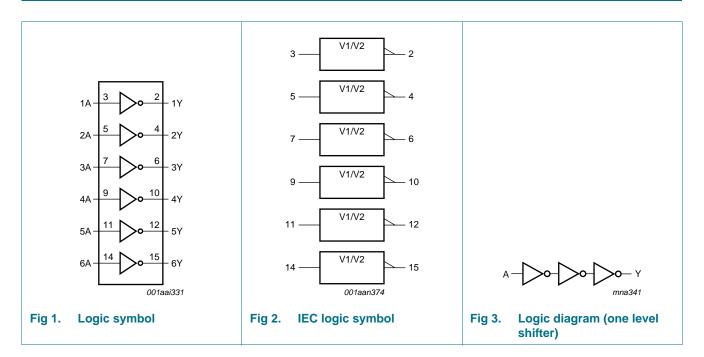
Table 1. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74HC4049N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4							
74HC4049D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1							
74HC4049DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1							
74HC4049PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							



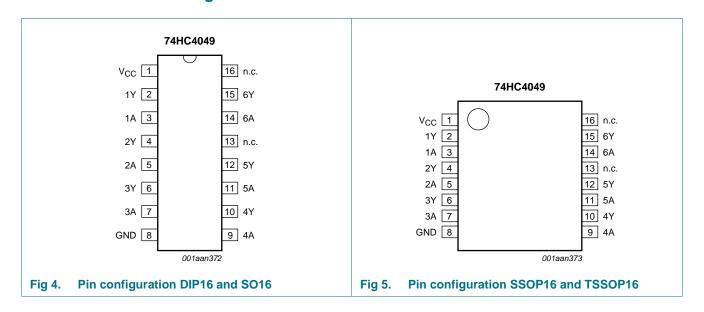
# Hex inverting HIGH-to-LOW level shifter

# 4. Functional diagram



# 5. Pinning information

### 5.1 Pinning



#### Hex inverting HIGH-to-LOW level shifter

# 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{CC}$	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

# 6. Functional description

Table 3. Function table [1]

Input	Output
nA	nY
L	Н
Н	L

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

# 7. Limiting values

Table 4. Limiting values

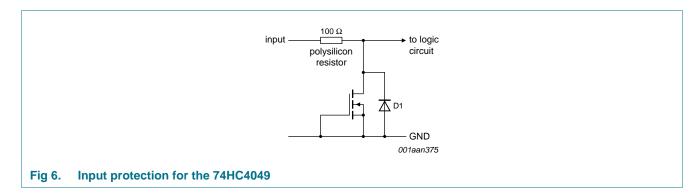
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
V <sub>IK</sub>	input clamping voltage		-0.5	+16	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V}$	-20	-	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	[1] _	750	mW
		SO16, SSOP16 and TSSOP16 packages	[2] _	500	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

<sup>[2]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

### Hex inverting HIGH-to-LOW level shifter



# 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		2.0	5.0	6.0	V
$V_{I}$	input voltage		0	-	15	V
Vo	output voltage		0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; V_{I} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; V_{I} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 15.0 \text{ V}$	-	-	83	ns/V

# 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	Ī
V <sub>IH</sub> HIGH-level input voltage		$V_{CC} = 2.0 \text{ V}$	1.5	1.3	-	1.5	-	1.5	-	V
	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V	
		$V_{CC} = 6.0 \text{ V}$	4.2	3.1	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	0.7	0.5	-	0.5	-	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	1.8	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.3	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$								
		$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A$ ; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

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### Hex inverting HIGH-to-LOW level shifter

**Table 6. Static characteristics** ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$								
		$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
		$V_I = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ 6.0 V	-	-	±0.5	-	±5.0	-	±5.0	μА
I <sub>CC</sub>	supply current	$V_I$ = 15 V or GND; $I_O$ = 0 A; $V_{CC}$ = 6.0 V	-	-	2.0	-	20	-	40	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

# 10. Dynamic characteristics

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub> propagation delay	propagation	nA to nY; see Figure 7	[1]								
	delay	$V_{CC} = 2.0 \text{ V}$		-	28	85	-	105	-	130	ns
		$V_{CC} = 4.5 \text{ V}$		-	10	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	8	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	8	14	-	18	-	22	ns
t <sub>t</sub>	transition	Yn; see Figure 7	[2]								
	time	$V_{CC} = 2.0 \text{ V}$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	19	ns

#### Hex inverting HIGH-to-LOW level shifter

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \ pF$  unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	Conditions	T <sub>an</sub>	<sub>nb</sub> = 25	°C		-40 °C 85 °C	T <sub>amb</sub> = to +1	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	-	14	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

fo = output frequency in MHz;

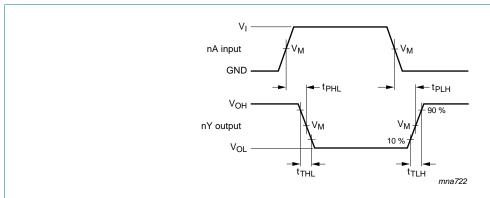
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

### 11. Waveforms



Measurement points are given in Table 8.

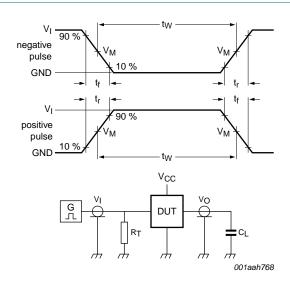
V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig 7. The input (nA) to output (nY) propagation delays

Table 8. Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC4049	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>

### Hex inverting HIGH-to-LOW level shifter



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

S1 = Test selection switch.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

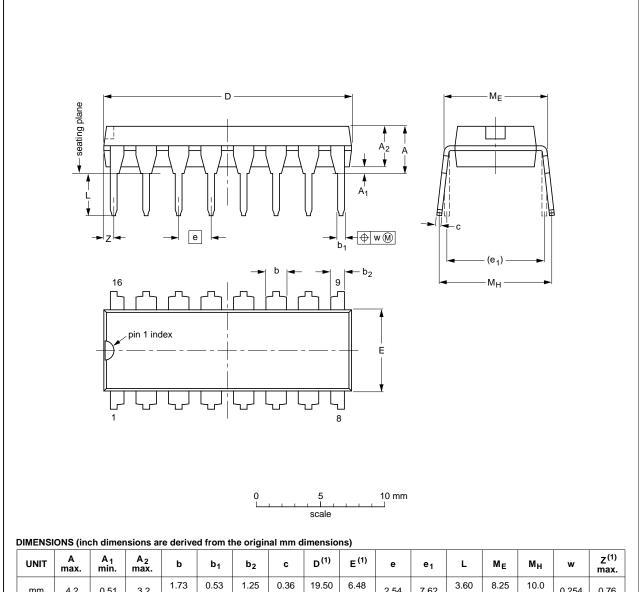
Туре	Input		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC4049	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

### Hex inverting HIGH-to-LOW level shifter

# 12. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	. A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inche	s 0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT38-4					<del>95-01-14</del> 03-02-13	

Fig 9. Package outline SOT38-4 (DIP16)

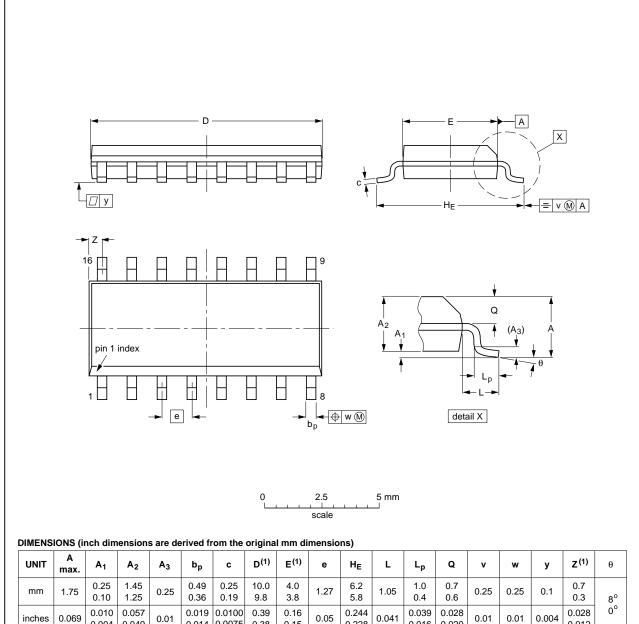
74HC4049

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#### Hex inverting HIGH-to-LOW level shifter

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### 0.069 inches 0.004

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 0.0075

0.38

0.15

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

0.228

0.016

0.020

Fig 10. Package outline SOT109-1 (SO16)

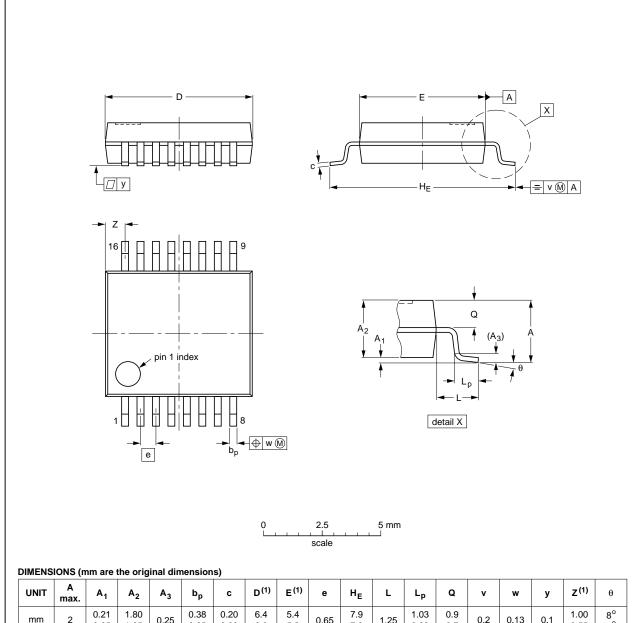
0.049

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### Hex inverting HIGH-to-LOW level shifter

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



							-,												
ı	JNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
	mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

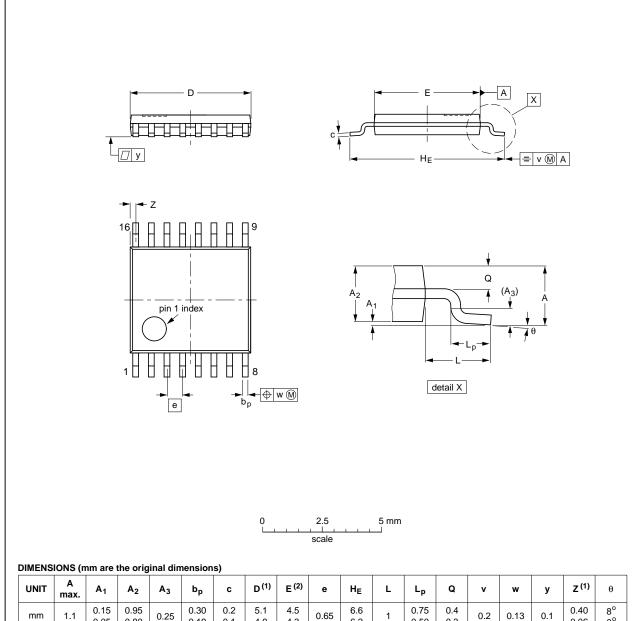
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				<del>99-12-27</del> 03-02-19
					—	00 02 10

Fig 11. Package outline SOT338-1 (SSOP16)

### Hex inverting HIGH-to-LOW level shifter

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



#### 0.15 0.95 mm 1.1

0.05

0.80

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

0.19

2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig 12. Package outline SOT403-1 (TSSOP16)

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# Hex inverting HIGH-to-LOW level shifter

# 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4049 v.6	20130108	Product data sheet	-	74HC4049 v.5
Modifications:	<ul> <li>New gener</li> </ul>	al description.		
74HC4049 v.5	20120803	Product data sheet	-	74HC4049 v.4
Modifications:	<ul> <li>Measurement</li> </ul>	ent points added to figure	7 (errata).	
74HC4049 v.4	20111212	Product data sheet	-	74HC4049 v.3
74HC4049 v.3	20101230	Product data sheet	-	74HC4049_CNV v.2
74HC4049_CNV v.2	19970827	Product specification	-	-

#### Hex inverting HIGH-to-LOW level shifter

# 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### Hex inverting HIGH-to-LOW level shifter

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For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

# Hex inverting HIGH-to-LOW level shifter

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